



2SC5476

85V/3A Driver Applications

Applications

- Suitable for use in switching of L load (motor drivers, printer hammer drivers, relay drivers).

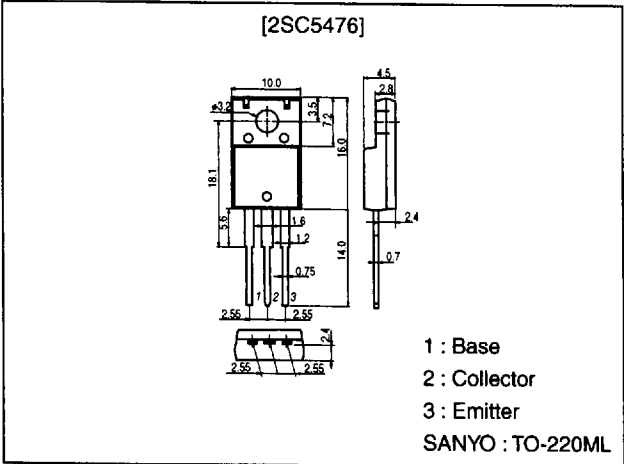
Features

- High DC current gain.
- Large current capacity and wide ASO.
- Contains a Zener diode of $95\pm10V$ between collector and base.
- Uniformity in collector-to-base voltage due to adoption of accurate impurity diffusion process.
- High inductive load handling capability.

Package Dimensions

unit:mm

2041A



Specifications

Absolute Maximum Ratings at $T_a = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		85*	V
Collector-to-Emitter Voltage	V_{CEO}		85*	V
Emitter-to-Base Voltage	V_{EBO}		6	V
Collector Current	I_C		3	A
Collector Current (Pulse)	I_{CP}		5	A
Base Current	I_B		0.5	A
Collector Dissipation	P_C		2	W
		$T_c=25^{\circ}C$	20	W
Junction Temperature	T_j		150	$^{\circ}C$
Storage Temperature	T_{stg}		-55 to +150	$^{\circ}C$

* : With a Zener diode of ($95\pm10V$).

Electrical Characteristics at $T_a = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=70V, I_E=0$			10	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=5V, I_C=0$			3	mA
DC Current Gain	h_{FE}	$V_{CE}=3V, I_C=1.5A$	2000	6000		
Gain-Bandwidth Product	f_T	$V_{CE}=5V, I_C=1.5A$		50		MHz
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=1.5A, I_B=3mA$		0.9	1.5	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=1.5A, I_B=3mA$			2.0	V

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- Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=0.1mA, I_E=0$	85	95	105	V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, R_{BE}=\infty$	85	95	105	V
Inductive Load Voltage	Es/b	$L=100mH, R_{BE}=100\Omega$	15			mJ

Es/b Test Circuit

